

BLF7G27L-75P; BLF7G27LS-75P

Power LDMOS transistor

Rev. 2 — 14 July 2010

Product data sheet

1. Product profile

1.1 General description

75 W LDMOS power transistor for base station applications at frequencies from 2300 MHz to 2700 MHz.

Table 1. Typical performance

Typical RF performance at $T_{case} = 25\text{ °C}$ in a common source class-AB production test circuit.

Mode of operation	f (MHz)	I _{DQ} (mA)	V _{DS} (V)	P _{L(AV)} (W)	G _p (dB)	η _D (%)	ACPR _{885k} (dBc)
IS-95	2300 to 2400	650	28	12	17	26	-46 ^[1]

[1] Single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on the CCDF. Channel bandwidth is 1.2288 MHz.

1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low R_{th} providing excellent thermal stability
- Designed for broadband operation (2300 MHz to 2700 MHz)
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent pre-distortability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

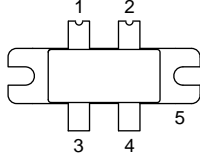
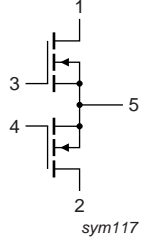
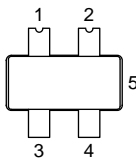
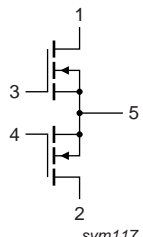
1.3 Applications

- RF power amplifiers for W-CDMA base stations and multi carrier applications in the 2300 MHz to 2700 MHz frequency range



2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
BLF7G27L-75P (SOT1121A)			
1	drain1		
2	drain2		
3	gate1		
4	gate2		
5	source		
[1]			
BLF7G27LS-75P (SOT1121B)			
1	drain1		
2	drain2		
3	gate1		
4	gate2		
5	source		
[1]			

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLF7G27L-75P	-	flanged LDMOST ceramic package; 2 mounting holes; 4 leads	SOT1121A
BLF7G27LS-75P	-	earless flanged LDMOST ceramic package; 4 leads	SOT1121B

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V_{GS}	gate-source voltage		-0.5	+13	V
I_D	drain current		-	18	A
T_{stg}	storage temperature		-65	+150	°C
T_j	junction temperature		-	225	°C

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	$T_{case} = 80\text{ °C}$; $P_L = 10\text{ W}$	0.5	K/W

6. Characteristics

Table 6. Characteristics

$T_j = 25\text{ °C}$; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0\text{ V}$; $I_D = 0.5\text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10\text{ V}$; $I_D = 50\text{ mA}$	1.3	1.8	2.3	V
I_{DSS}	drain leakage current	$V_{GS} = 0\text{ V}$; $V_{DS} = 28\text{ V}$	-	-	5	μA
I_{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75\text{ V}$; $V_{DS} = 10\text{ V}$	-	9.5	-	A
I_{GSS}	gate leakage current	$V_{GS} = 11\text{ V}$; $V_{DS} = 0\text{ V}$	-	-	500	nA
g_{fs}	forward transconductance	$V_{DS} = 10\text{ V}$; $I_D = 2.5\text{ A}$	-	3.8	-	S
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75\text{ V}$; $I_D = 3.5\text{ A}$	-	0.29	-	Ω

7. Test information

Table 7. Functional test information

Mode of operation: 1-carrier N-CDMA, single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on the CCDF; channel bandwidth is 1.2288 MHz; $f_1 = 2300\text{ MHz}$; $f_2 = 2400\text{ MHz}$; RF performance at $V_{DS} = 28\text{ V}$; $I_{Dq} = 650\text{ mA}$; $T_{case} = 25\text{ °C}$; 2 sections combined unless otherwise specified; in a class-AB production test circuit.

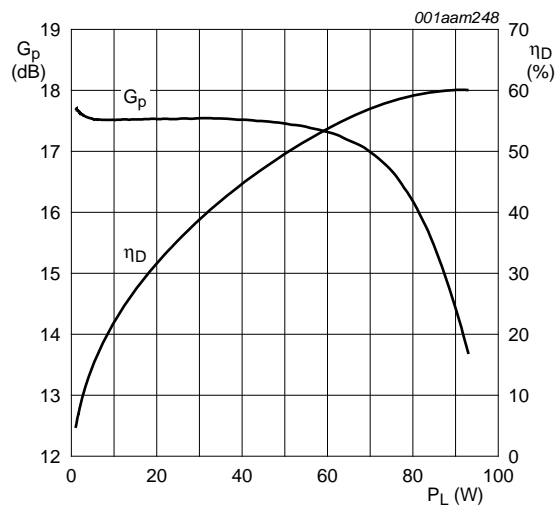
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$P_{L(AV)}$	average output power		-	12	-	W
G_p	power gain	$P_{L(AV)} = 12\text{ W}$	15.8	17	-	dB
RL_{in}	input return loss	$P_{L(AV)} = 12\text{ W}$	-	-12	-8	dB
η_D	drain efficiency	$P_{L(AV)} = 12\text{ W}$	23	26	-	%
$ACPR_{885k}$	adjacent channel power ratio (885 kHz)	$P_{L(AV)} = 12\text{ W}$	-	-46	-42	dBc

7.1 Ruggedness in class-AB operation

The BLF7G27L-75P and BLF7G27LS-75P are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:

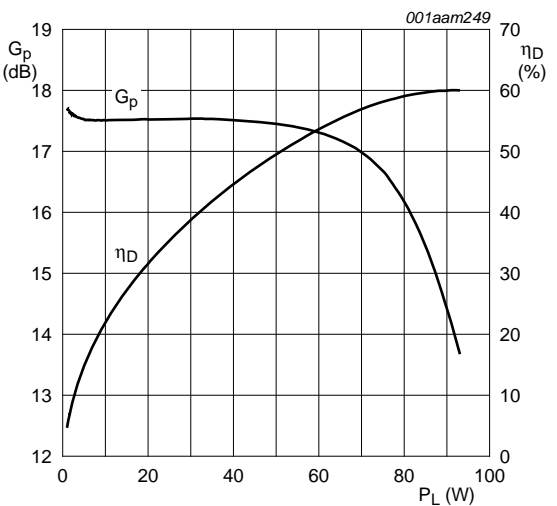
$V_{DS} = 28\text{ V}$; $I_{Dq} = 650\text{ mA}$; $P_L = 75\text{ W}$ (CW); $f = 2300\text{ MHz}$.

7.2 One-tone CW



$V_{DS} = 28\text{ V}$; $I_{Dq} = 650\text{ mA}$; $f = 2300\text{ MHz}$.

Fig 1. One-tone CW power gain and drain efficiency as function of load power; typical values

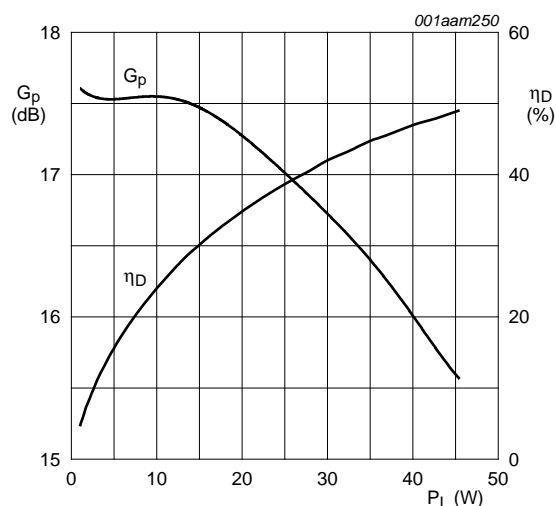


$V_{DS} = 28\text{ V}$; $I_{Dq} = 650\text{ mA}$; $f = 2400\text{ MHz}$.

Fig 2. One-tone CW power gain and drain efficiency as function of load power; typical values

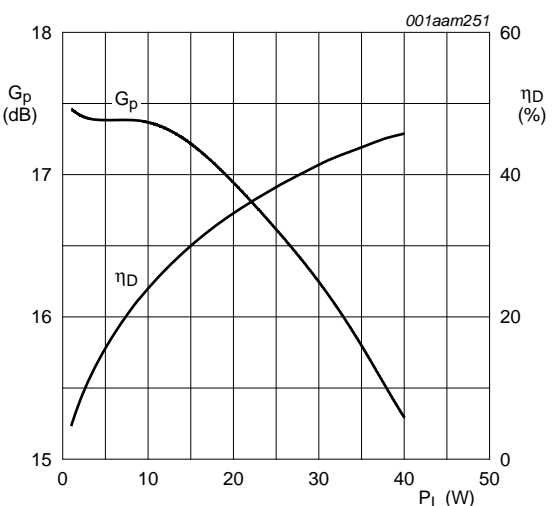
7.3 Single carrier IS-95

Single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13).
PAR = 9.7 dB at 0.01 % probability on the CCDF. Channel bandwidth is 1.2288 MHz.



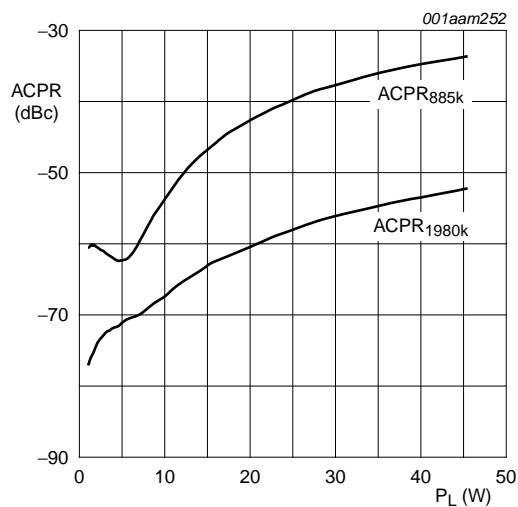
$V_{DS} = 28\text{ V}$; $I_{Dq} = 650\text{ mA}$; $f = 2300\text{ MHz}$.

Fig 3. Single carrier IS-95 power gain and drain efficiency as function of load power; typical values



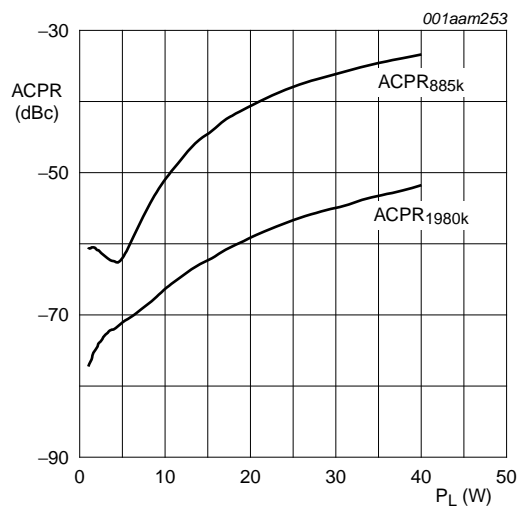
$V_{DS} = 28\text{ V}$; $I_{Dq} = 650\text{ mA}$; $f = 2400\text{ MHz}$.

Fig 4. Single carrier IS-95 power gain and drain efficiency as function of load power; typical values



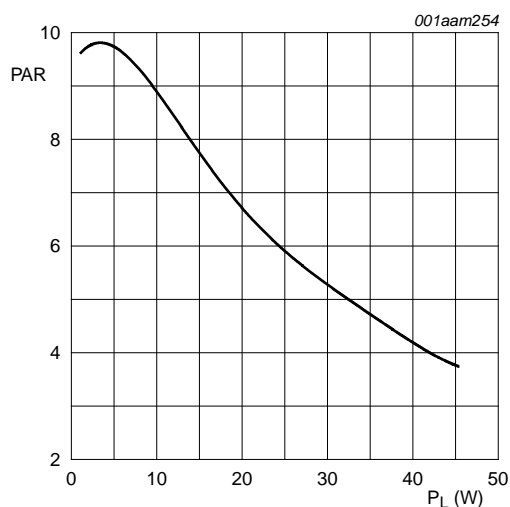
$V_{DS} = 28$ V; $I_{DQ} = 650$ mA; $f = 2300$ MHz.

Fig 5. Single carrier IS-95 ACPR at 885 kHz and at 1980 kHz as function of load power; typical values



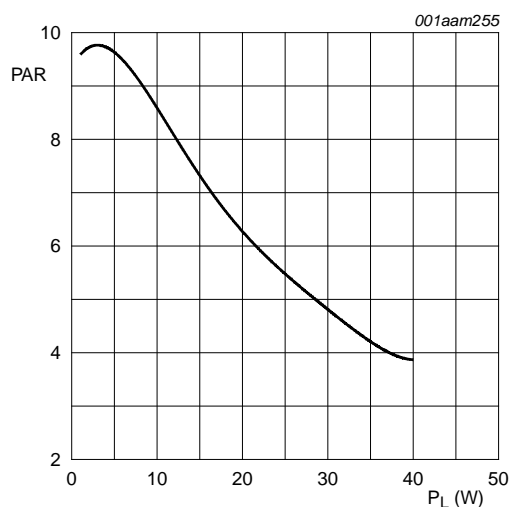
$V_{DS} = 28$ V; $I_{DQ} = 650$ mA; $f = 2400$ MHz.

Fig 6. Single carrier IS-95 ACPR at 885 kHz and at 1980 kHz as function of load power; typical values



$V_{DS} = 28$ V; $I_{DQ} = 650$ mA; $f = 2300$ MHz.

Fig 7. Single carrier IS-95 peak-to-average power ratio as a function of load power; typical values

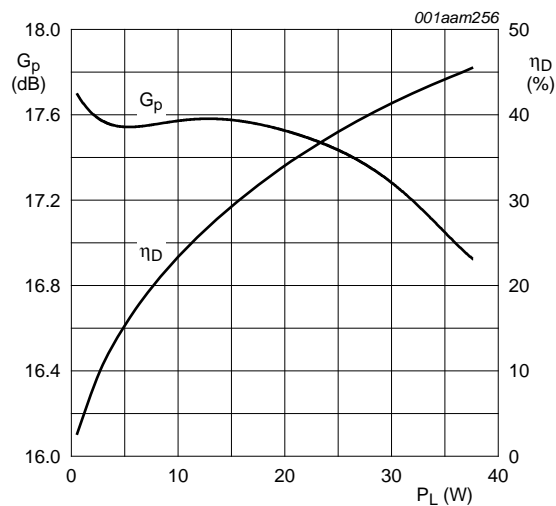


$V_{DS} = 28$ V; $I_{DQ} = 650$ mA; $f = 2400$ MHz.

Fig 8. Single carrier IS-95 peak-to-average power ratio as a function of load power; typical values

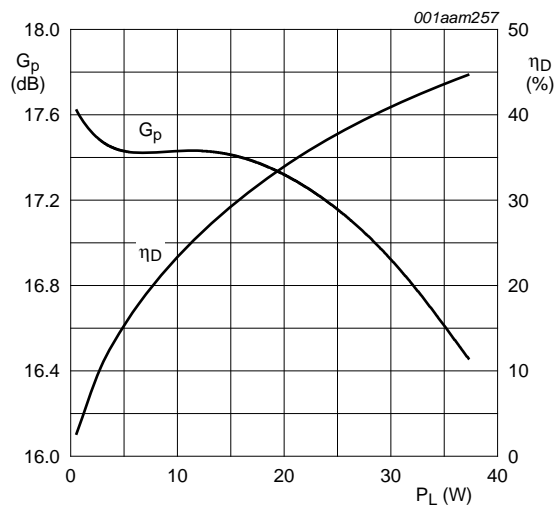
7.4 Single carrier W-CDMA

3GPP; test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability on CCDF.
Channel bandwidth is 3.84 MHz.



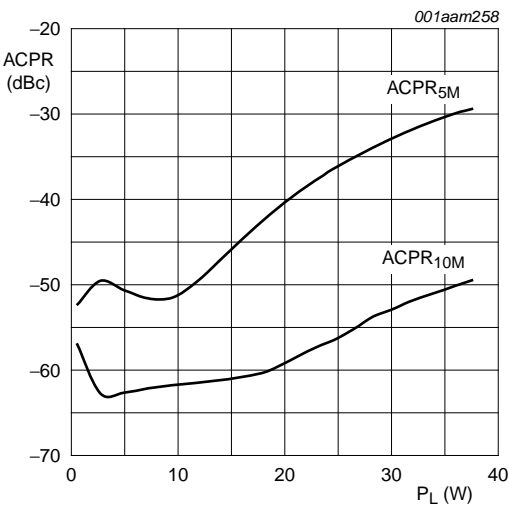
$V_{DS} = 28\text{ V}$; $I_{DQ} = 650\text{ mA}$; $f = 2300\text{ MHz}$.

Fig 9. Single carrier W-CDMA power gain and drain efficiency as function of load power; typical values



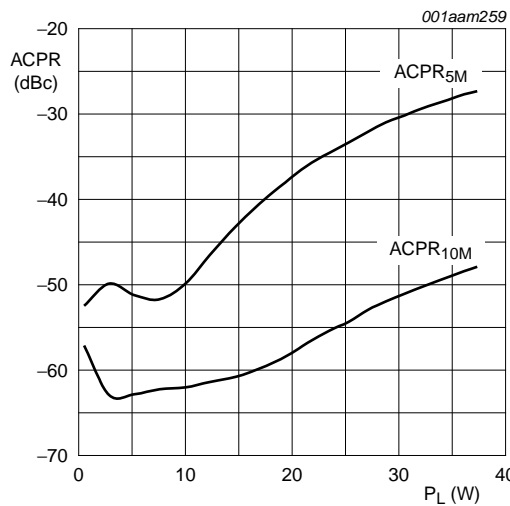
$V_{DS} = 28\text{ V}$; $I_{DQ} = 650\text{ mA}$; $f = 2400\text{ MHz}$.

Fig 10. Single carrier W-CDMA power gain and drain efficiency as function of load power; typical values



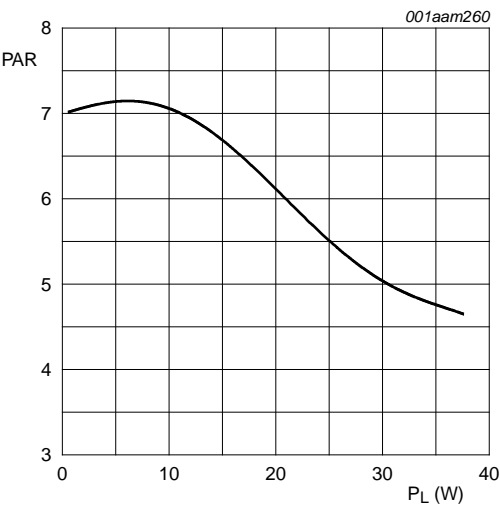
$V_{DS} = 28\text{ V}$; $I_{DQ} = 650\text{ mA}$; $f = 2300\text{ MHz}$.

Fig 11. Single carrier W-CDMA ACPR at 5 MHz and at 10 MHz as function of load power; typical values



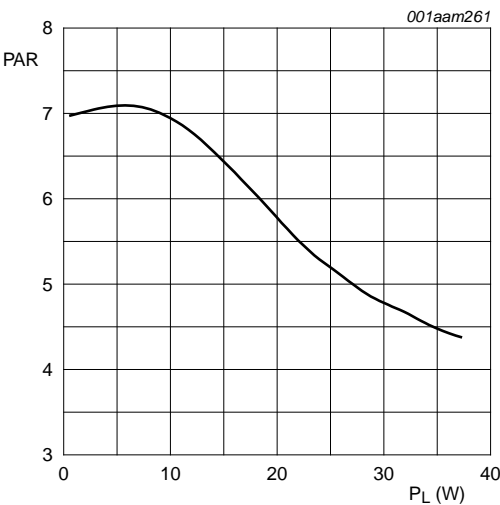
$V_{DS} = 28\text{ V}$; $I_{DQ} = 650\text{ mA}$; $f = 2400\text{ MHz}$.

Fig 12. Single carrier W-CDMA ACPR at 5 MHz and at 10 MHz as function of load power; typical values



$V_{DS} = 28\text{ V}$; $I_{DQ} = 650\text{ mA}$; $f = 2300\text{ MHz}$.

Fig 13. Single carrier W-CDMA peak-to-average power ratio as a function of load power; typical values



$V_{DS} = 28\text{ V}$; $I_{DQ} = 650\text{ mA}$; $f = 2400\text{ MHz}$.

Fig 14. Single carrier W-CDMA peak-to-average power ratio as a function of load power; typical values

8. Package outline

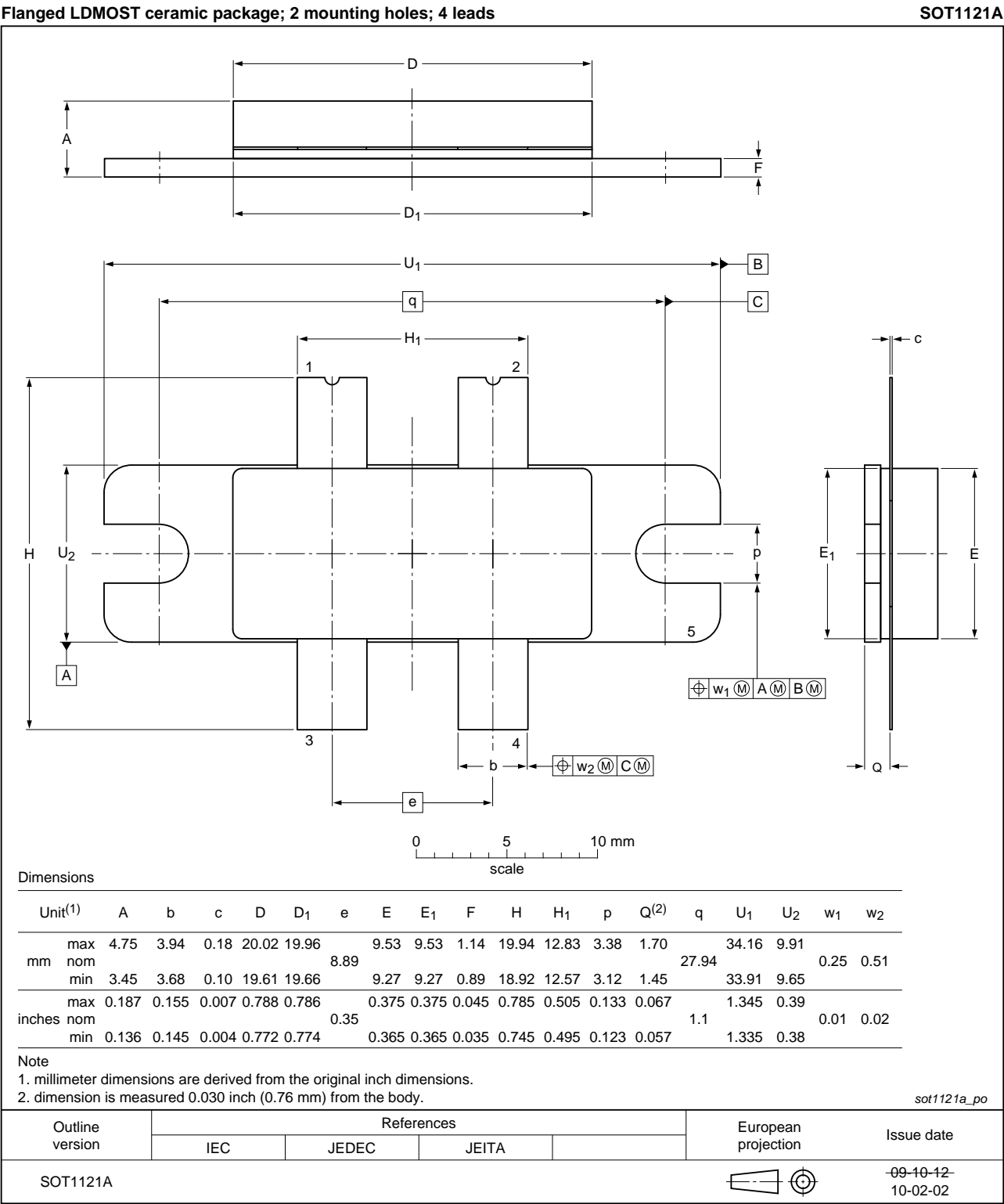


Fig 15. Package outline SOT1121A

Earless flanged LDMOST ceramic package; 4 leads

SOT1121B

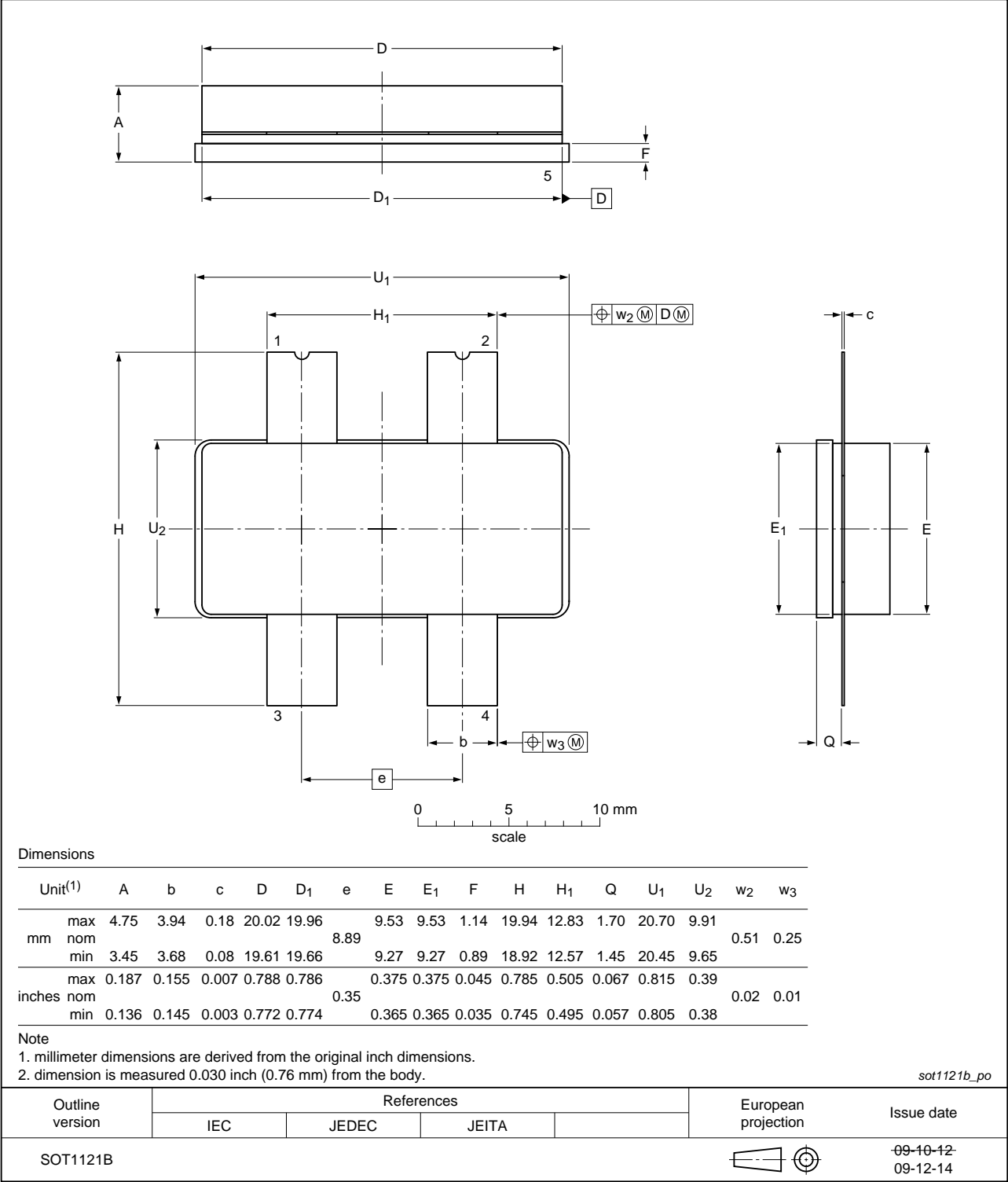


Fig 16. Package outline SOT1121B

9. Abbreviations

Table 8. Abbreviations

Acronym	Description
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
3GPP	3rd Generation Partnership Project
IS-95	Interim Standard 95
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal Oxide Semiconductor
LDMOST	Laterally Diffused Metal Oxide Semiconductor Transistor
N-CDMA	Narrowband Code Division Multiple Access
PAR	Peak-to-Average power Ratio
RF	Radio Frequency
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

10. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF7G27L-75P_BLF7G27LS-75P v.2	20100714	Product data sheet	-	BLF7G27L-75P_ BLF7G27LS-75P v.1
Modifications: <ul style="list-style-type: none"> • The status of this document has been changed to "Preliminary data sheet". • Table 1 on page 1: changed the value of ACPR_{885k} to -46 dBc. • Table 4 on page 2: added the maximum value of I_D. • Table 5 on page 3: changed several values. • Table 6 on page 3: changed several values. • Table 7 on page 3: changed several values. • Section 7.1 on page 3: changed the value of P_L. • Added Section 7.2 on page 4. • Added Section 7.3 on page 4. • Added Section 7.4 on page 6. 				
BLF7G27L-75P_BLF7G27LS-75P v.1	20100329	Objective data sheet	-	-

11. Legal information

11.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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